

# **500V N-Channel MOSFET**

#### FEATURES

- Fast switching
- Integrate fast recovery diode
- Fast switching speed
- 100% avalanche tested
- Improved dv/dt capability

#### APPLICATIONS

- Switch Mode Power Supply (SMPS)
- Motor Controls
- Power Factor Correction (PFC)

<b>Device Marking and Package Information</b>				
Device	Package Marking			
TMA7N50HF	TO-220F	A7N50HF		
TMD7N50HF	TO-252	D7N50HF		
TMU7N50HF	TO-251	U7N50HF		
TMP7N50HF	TO-220	P7N50HF		

TO-220F GDS	TO-252 G <sup>D</sup> S	TO-251 GDS
<b>RoHS</b> mation	TO-220 GDS	G

Absolute Maximum Ratings $T_c = 25^{\circ}C$ , unless otherwise noted						
	Symbol	Value			11	
Parameter		TO-220F	TO-252	TO-251	TO-220	Unit
Drain-Source Voltage ( $V_{GS} = 0V$ )	V <sub>DSS</sub>		50	00		V
Continuous Drain Current	I <sub>D</sub>	7		А		
Pulsed Drain Current (note1)	I <sub>DM</sub>	28		A		
Gate-Source Voltage	V <sub>GSS</sub>	±30		V		
Single Pulse Avalanche Energy (note2)	E <sub>AS</sub>	176		mJ		
Avalanche Current (note1)	I <sub>AR</sub>	4.2		А		
Repetitive Avalanche Energy (note1)	E <sub>AR</sub>	35		mJ		
Power Dissipation ( $T_c = 25^{\circ}C$ )	P <sub>D</sub>	54 83		W		
Operating Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55~+150		°C		

Thermal Resistance						
Desembles	Cumhal	Value				
Parameter	Symbol TO-	TO-220F	TO-252	TO-251	TO-220	Unit
Thermal Resistance, Junction-to-Case	R <sub>thJC</sub>	2.3		1.5	-	°C/W
Thermal Resistance, Junction-to-Ambient	R <sub>thJA</sub>	62.5		60		°C/W

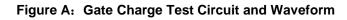


<b>Specifications</b> T <sub>J</sub> = 25°C, ur	less othe	rwise noted					
Deservator	Sumhal Tast Canditiana	Value			Unit		
Parameter	Symbol Test Conditions -		Min.	Тур.	Max.		
Static							
Drain-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	$V_{GS} = 0V, I_{D} = 250\mu A$	500			V	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS} = 500V, V_{GS} = 0V, T_{J} = 25^{\circ}C$			1	μA	
Gate-Source Leakage	I <sub>GSS</sub>	$V_{GS}$ = $\pm 30V$			±100	nA	
Gate-Source Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 250 \mu A$	3.0		4.0	V	
Drain-Source On-Resistance (Note3)	R <sub>DS(on)</sub>	V <sub>GS</sub> = 10V, I <sub>D</sub> = 3.5A		1.1	1.3	Ω	
Dynamic			-				
Input Capacitance	C <sub>iss</sub>	$\gamma = 0 \gamma$		700		pF	
Output Capacitance	C <sub>oss</sub>	$V_{GS} = 0V,$ $V_{DS} = 25V,$		94			
Reverse Transfer Capacitance	C <sub>rss</sub>	f = 1.0MHz		12			
Total Gate Charge	Q <sub>g</sub>			19		nC	
Gate-Source Charge	Q <sub>gs</sub>	$V_{DD} = 400V, I_{D} = 7A, V_{GS} = 10V$		3.7			
Gate-Drain Charge	$Q_{gd}$			11			
Turn-on Delay Time	t <sub>d(on)</sub>			13			
Turn-on Rise Time	t <sub>r</sub>	V <sub>DD</sub> = 250V, I <sub>D</sub> = 7A,		20			
Turn-off Delay Time	t <sub>d(off)</sub>	$R_{G} = 25 \Omega$		76		ns	
Turn-off Fall Time	t <sub>f</sub>			40			
Drain-Source Body Diode Character	istics						
Continuous Body Diode Current	۱ <sub>s</sub>	T 05.00			7	٨	
Pulsed Diode Forward Current	I <sub>SM</sub>	T <sub>C</sub> = 25 °C			28	A	
Body Diode Voltage	V <sub>SD</sub>	T <sub>J</sub> = 25°C, I <sub>SD</sub> = 7A, V <sub>GS</sub> = 0V			1.4	V	
Reverse Recovery Time	t <sub>rr</sub>	V <sub>GS</sub> = 0V,I <sub>S</sub> = 7A,		87		ns	
Reverse Recovery Charge	Q <sub>rr</sub>	di <sub>F</sub> /dt =100A /µs		0.42		μC	

#### Notes

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature
- 2.  $I_{AS}$  = 4.2A,  $V_{DD}$  = 50V,  $R_{G}$  = 25  $\Omega$ , Starting  $T_{J}$  = 25 °C
- 3. Pulse Test: Pulse width  $\leq$  300µs, Duty Cycle  $\leq$  1%





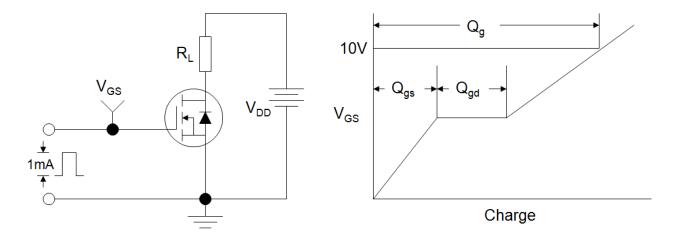


Figure B: Resistive Switching Test Circuit and Waveform

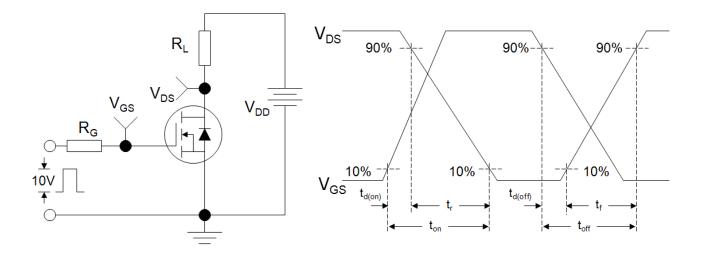
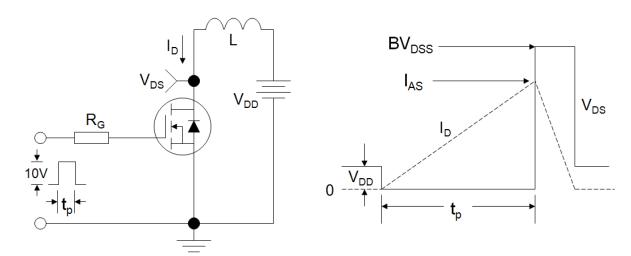
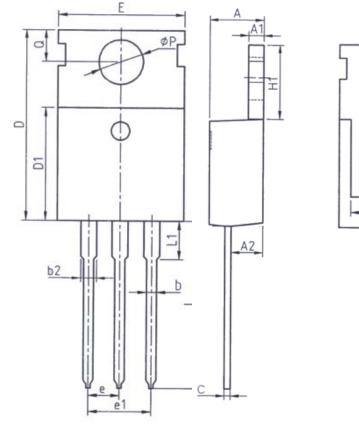
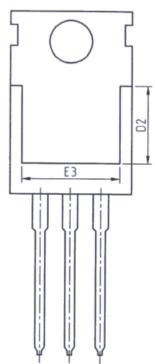


Figure C: Unclamped Inductive Switching Test Circuit and Waveform



**TO-220** 

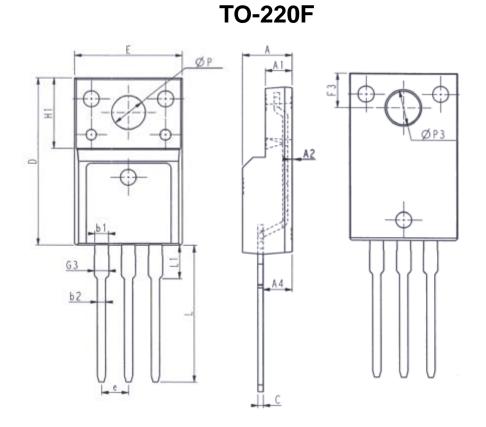




Unit: mm				
Symbol	Min.	Max.		
Α	4.37	4.77		
A1	1.25	1.45		
A2	2. 20	2.60		
b	0.70	0.95		
b2	1.17	1.47		
С	0.40	0.65		
D	15.10	16. 10		
D1	8.80	9.40		
D2	5.50	-		

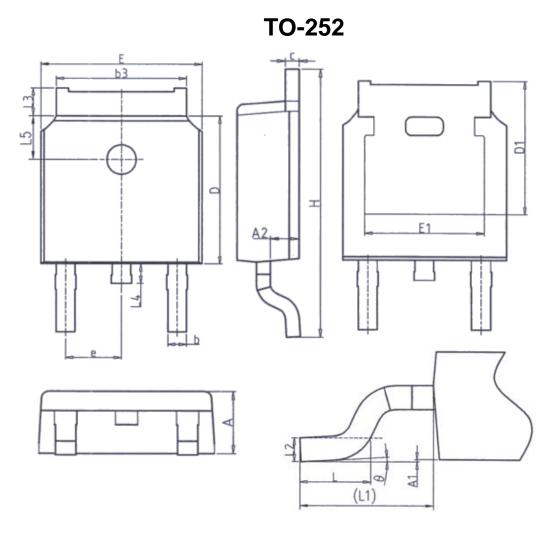
Unit: mm				
Symbol	Min.	Max.		
E	9.70	10. 30		
E3	7.00	-		
e	2.54BSC			
e1	5. 08	BSC		
H1	6. 25	6.85		
L	12.75	13.80		
L1	- 3.40			
Р	3. 40	3.80		
Q	2.60	3.00		





Unit: mm			l	Jnit: mm	n
Symbol	Min.	Max.	Symbol	Min.	Max.
E	9.96	10.36	L	12. 68	13. 28
Α	4.50	4.90	L1	2.93	3.13
A1	2.34	2.74	Р	3.03	3. 38
A2	0.30	0.60	P3	3. 15	3.65
A4	2.56	2.96	F3	3. 15	3. 45
с	0.40	0.65	G3	1.25	1.55
D	15. 57	16. 17	b1	1.18	1.43
H1	6. 70REF		b2	0.70	0.95
е	2.54BSC				

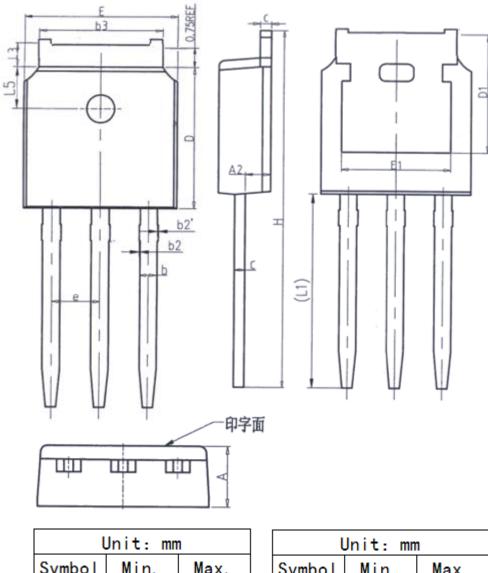




Unit: mm				
Symbol	Min.	Max.		
Α	2.20	2.40		
A1	0.00	0.20		
A2	0.97	1.17		
b	0.68	0.90		
b3	5.20	5.50		
с	0.43	0.63		
D	5.98	6. 22		
D1	D1 5. 30REF			
E	6.40	6.80		
E1	4.63	_		

Unit: mm				
Symbol	Min.	Max.		
е	2. 28	6BSC		
Н	9.40	10.50		
L	1.38	1.75		
L1	2.90REF			
L2	0, 51	BSC		
L3	0.88	1.28		
L4	- 1.00			
L5	1.65 1.95			
θ	0°	8°		





**TO-251** 

Unit: mm				
Symbol	Min.	Max.		
Α	2.20	2.40		
A2	0.97	1.17		
b	0. 68	0.90		
b2	0.00	0.10		
b2′	0.00	0.10		
b3	5.20	5.50		
с	0.43	0.63		
D	5.98	6. 22		

Unit: mm				
Symbol	Min.	Max.		
D1	5.30	OREF		
E	6.40	6.80		
E1	4.63	-		
е	2. 286BSC			
Н	16. 22	16.82		
L1	9.15	9.65		
L3	0.88	1. 28		
L5	1.65	1.95		



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